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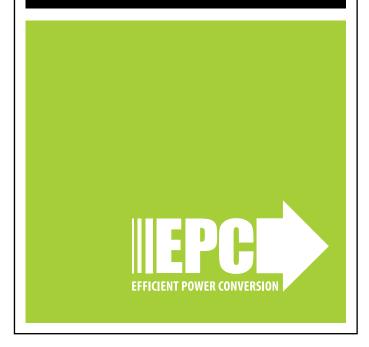
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Development Board EPC9004 Quick Start Guide

200 V Half-Bridge with Gate Drive, Using EPC2012



DESCRIPTION

The EPC9004 development board is a 200 V maximum device voltage, 2 A maximum output current, half bridge with onboard gate drives, featuring the EPC2012 enhancement mode (*eGaN*[®]) field effect transistor (FET). The purpose of this development board is to simplify the evaluation process of the EPC2012 *eGaN* FET by including all the critical components on a single board that can be easily connected into any existing converter.

The EPC9004 development board is 2" x 1.5" and contains not only two EPC2012 *eGaN* FET in a half bridge configuration using two

Texas Instruments UCC27611 gate drivers as well as supply and bypass capacitors. The board contains all critical components and layout for optimal switching performance. There are also various probe points to facilitate simple waveform measurement and efficiency calculation. A complete block diagram of the circuit is given in Figure 1.

For more information on the EPC2012 *eGaN* FET please refer to the datasheet available from EPC at www.epc-co.com. The datasheet should be read in conjunction with this quick start guide.

Table 1: Performance Summary (TA = 25°C)							
SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNITS		
$V_{\rm DD}$	Gate Drive Input Supply Range		7	12	V		
$V_{\rm IN}$	Bus Input Voltage Range			150	V		
V _{OUT}	Switch Node Output Voltage			200	V		
I _{OUT}	Switch Node Output Current			2*	A		
V _{PWM}	PWM Logic Input Voltage Threshold	Input 'High'	3.5	6	V		
		Input 'Low'	0	1.5	V		
	Minimum 'High' State Input Pulse Width	VPWM rise and fall time < 10ns	100		ns		
	Minimum 'Low' State Input Pulse Width	VPWM rise and fall time < 10ns	500#		ns		

* Assumes inductive load, maximum current depends on die temperature – actual maximum current with be subject to switching frequency, bus voltage and thermals.

Dependent on time needed to 'refresh' high side bootstrap supply voltage.

Quick Start Procedure

Development board EPC9004 is easy to set up to evaluate the performance of the EPC2012 eGaN FET. Refer to Figure 2 for proper connect and measurement set of the procedure below:

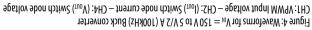
- 1. With power off, connect the input power supply bus to $+V_{IN}$ (J5, J6) and ground / return to $-V_{IN}$ (J7, J8).
- 2. With power off, connect the switch node of the half bridge V_{out} (J3, J4) to your circuit as required.
- 3. With power off, connect the gate drive input to $+V_{DD}$ (11, Pin-1) and ground return to $-V_{DD}$ (11, Pin-2).
- 4. With power off, connect the input PWM control signal to PWM (J2, Pin-1) and ground return to any of the remaining J2 pins.
- 5. Turn on the gate drive supply make sure the supply is between 7 V and 12 V range.
- 6. Turn on the bus voltage to the required value (do not exceed the absolute maximum voltage of 200 V on V₀₀₁).
- 7. Turn on the controller / MWH input source and probe switching node to see switching operation.
- Once operational, adjust the bus voltage and load PWM control within the operating range and observe the output switching behavior, efficiency and other parameters.
- 9. For shutdown, please follow steps in reverse.

DUE. When measuring the high frequency content switch node (OUT), care must be taken to avoid long ground leads. Measure the Switch node (OUT) by placing the oscilloscope probe tip through the large via on the switch node (designed for this purpose) and grounding the probe directly across the GND terminals provided. See Figure 3 for proper scope probe technique.

ZHERMAL CONSIDERATIONS

The EPC9004 development board showcases the EPC2012 eGaN FET. Although the electrical performance surpasses that for traditional Si devices, the the readitional Si devices, the the the the the management requirements. The EPC9004 is intended for bench evaluation with low ambient temperature and convection cooling. The addition of heat-sinking and forced air cooling can significantly increase the current rating of these electrices, but care must be taken to not exceed the absolute maximum die temperature of 125°C.

NOTE. The EPC9004 development board does not have any current or thermal protection on board.



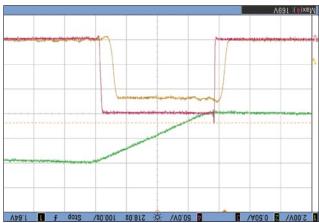
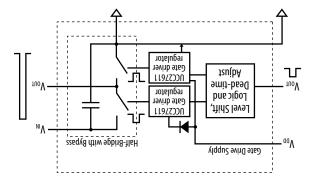


Figure 1: Block Diagram of EPC9004 Development Board



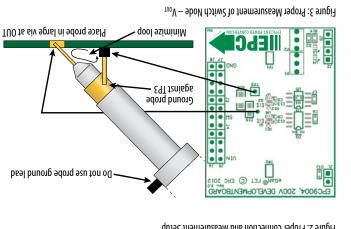


Figure 2: Proper Connection and Measurement Setup

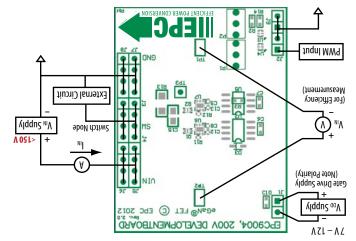
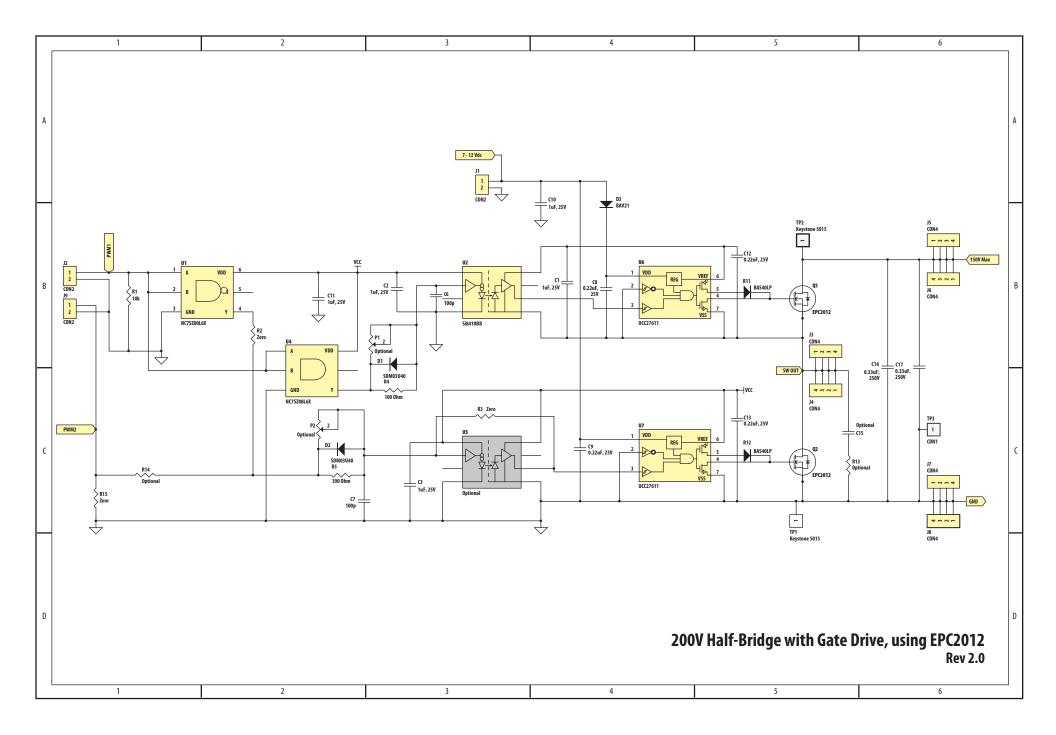


Table 2 : Bill of Material						
ltem	Qty	Reference	Part Description	Manufacturer / Part #		
1	4	C2, C3, C10, C11	Capacitor, 1uF, 10%, 25V, X5R	Murata, GRM188R61E105KA12D		
2	2	C6, C7	Capacitor, 100pF, 5%, 50V, NP0	TDK, C1608C0G1H101J		
3	3	C16, C17	Capacitor, 0.33uF, 10%, 250V, X7R	TDK, C4532X7R2E334M		
4	4	C8, C9, C12, C13	Capacitor, 0.22uF, 10%, 16V, X7R	TDK, C1005X7R1C224K		
5	2	D1, D2	Schottky Diode, 30V	Diodes Inc., SDM03U40-7		
6	1	D3	Diode, 200V	Diodes Inc.,BAV21WS-7-F		
7	1	J1	Connector	2pins of Tyco, 4-103185-0		
8	1	J2	Connector	4pins of Tyco, 4-103185-0		
9	1	J3, J4, J5, J6, J7, J8	Connector	FCI, 68602-224HLF		
10	2	Q1, Q2	eGaN FET	EPC, EPC2012		
11	1	R1	Resistor, 10.0K, 5%, 1/8W	Stackpole, RMCF0603FT10K0		
12	3	R2, R3, R15	Resistor, 0 Ohm, 1/8W	Stackpole, RMCF0603FT00R0		
13	2	R11, R12	Diode, 40V	Diodes Inc.,BAS40LP-7		
14	1	R4	Resistor, 100 Ohm, 1%, 1/8W	Stackpole, RMCF0603FT100R		
15	1	R5	Resistor, 390 Ohm, 1%, 1/8W	Stackpole, RMCF0603FT390R		
16	2	TP1, TP2	Test Point	Keystone Elect, 5015		
17	1	ТРЗ	Connector	1/40th of Tyco, 4-103185-0		
18	1	U1	I.C., Logic	Fairchild, NC7SZ00L6X		
19	1	U2	I.C., Isolator	Silicon Laboratories, Si8410BB		
20	1	U4	I.C., Logic	Fairchild, NC7SZ08L6X		
21	2	U6, U7	I.C., Gate driver	Texas Instruments, UCC27611		
22	0	C1, C15	Optional capacitor			
23	0	P1, P2	Optional Potentiometer			
24	0	R13, R14	Optional resistor			
25	0	U5	Optional I.C.			



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